

Supporting information

Polymeric Hole Transport Materials for Red CsPbI₃ Perovskite

Quantum-dot Light-emitting Diodes

Zong-Liang Tseng^{1*}, Shih-Hung Lin², Jian-Fu Tang³, Yu-Ching Huang⁴, Hsiang-Chih Cheng⁵, Wei-Lun Huang¹, Yi-Ting Lee⁶ and Lung-Chien Chen^{5*}

¹Department of Electronic Engineering and ⁴Department of Materials Engineering, Ming Chi University of Technology, No. 84, Gungjuan Rd., New Taipei City 24301, Taiwan.

²Department of Electronic Engineering and ³Bachelor Program in Interdisciplinary Studies, National Yunlin University of Science and Technology, Yunlin 64002, Taiwan.

⁵Department of Electro-optical Engineering, National Taipei University of Technology, 1, Sec.3, Chung-Hsiao E. Rd., Taipei 106, Taiwan.

⁶Center for Organic Photonics and Electronics Research (OPERA) Kyushu University 744 Motooka, Nishi, Fukuoka 819-0395, Japan.

*Corresponding authors. E-mail:

zltseeng@mail.mcut.edu.tw (Z. L. Tseng)

ocean@ntut.edu.tw (L. C. Chen)

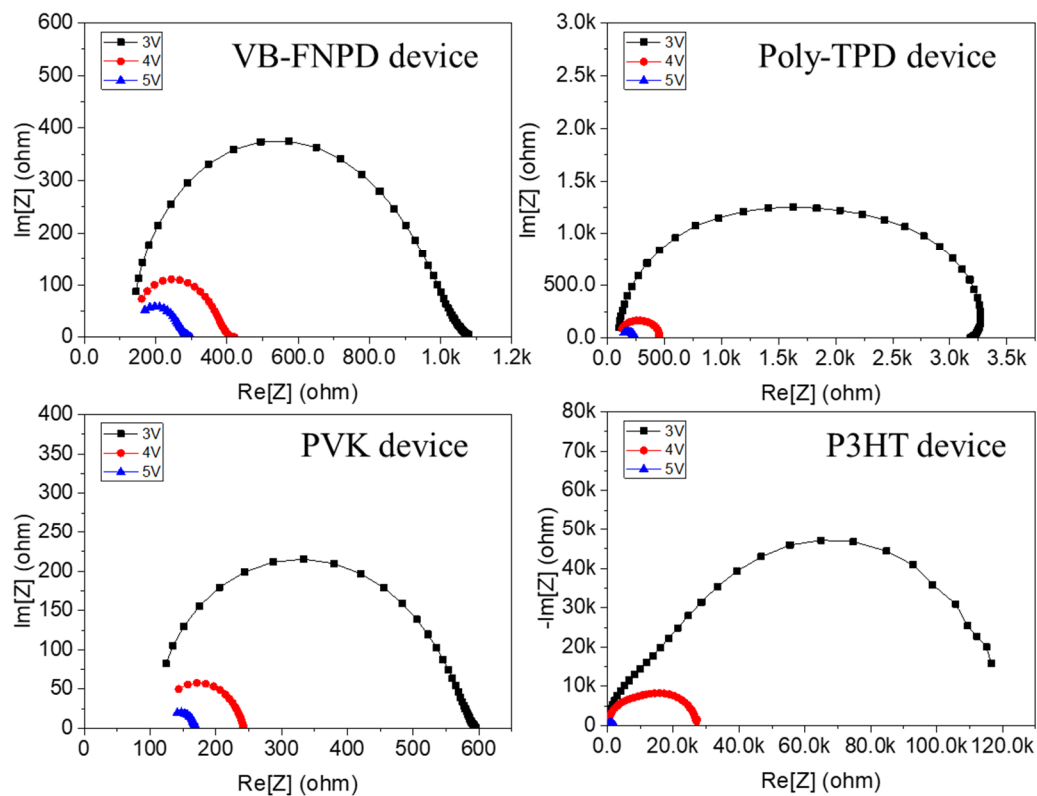


Figure S1 Impedance characteristics of IPQLED devices with different HTLs.